NSN 5961-00-828-4093

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-828-4093 **Inclosure Material:** Ceramic or glass **Overall Length:** Between 0.800 inches and 0.840 inches **Overall Diameter:** Between 0.246 inches and 0.250 inches **Function For Which Designed:** Microwave **Mounting Method:** Press fit **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 3.0 reverse breakdown voltage, dc **Power Rating Per Characteristic:** 10.0 milliwatts any acceptable absolute **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 1 pin and 1 flange Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig: A110a0